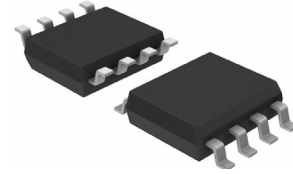


Low Power Dissipation, High-Precise, Rail-to-Rail Input and Output Operational Amplifier

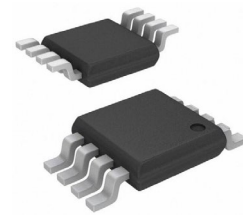
PRODUCT DESCRIPTION

The MS8231/8232 is a single-channel or a dual-channel rail-to-rail input and output operational amplifier with single power supply. These characteristics like low power dissipation and high precision make itself suitable for battery-powered system and portable electronic system.

The MS8231/8232 has stable unit gain and 13kHz signal bandwidth, making itself suitable for battery current detection and sensor signal processing circuits.



SOP8



MSOP8

FEATURES

- Rail-to-Rail Input and Output
- Low Offset Voltage (Max): $\pm 0.75\text{mV}$
- Low Quiescent Current: $1\mu\text{A}$
- Power Supply Voltage: 1.8V to 5.5V
- Gain Bandwidth: 13kHz
- Temperature Range: -40°C to 120°C

APPLICATIONS

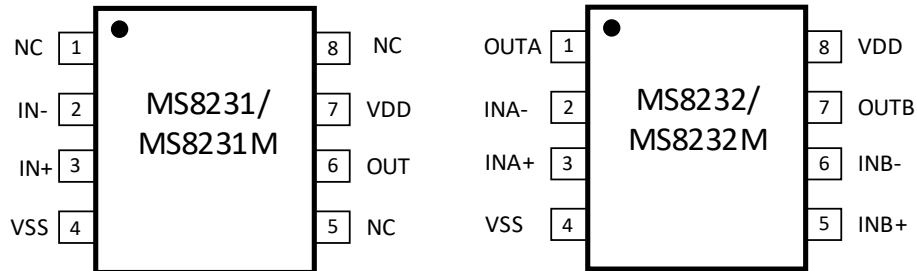
- Barcode Scanner
- Sensor
- Battery Current Detection
- Portable Electronic Product

PRODUCT SPECIFICATION

Part Number	Package	Marking
MS8231	SOP8	MS8231
*MS8231M	MSOP8	MS8231M
*MS8232	SOP8	MS8232
MS8232M	MSOP8	MS8232M

* The package is not available temporarily. If necessary, please contact Hangzhou Ruimeng Sales Department Center.

PIN CONFIGURATION



PIN DESCRIPTION

Pin	Name	Type	Description
MS8231/MS8231M			
1	NC	-	Not Connection
2	IN-	I	Negative Input
3	IN+	I	Positive Input
4	VSS	-	Negative Power Supply
5	NC	-	Not Connection
6	OUT	O	Channel Output
7	VDD	-	Positive Power Supply
8	NC	-	Not Connection
MS8232/MS8232M			
1	OUTA	O	Channel A Output
2	INA-	I	Negative Input (Channel A)
3	INA+	I	Positive Input (Channel A)
4	VSS	-	Negative Power Supply
5	INB+	I	Positive Input (Channel B)
6	INB-	I	Negative Input (Channel B)
7	OUTB	O	Channel B Output
8	VDD	-	Positive Power Supply

ABSOLUTE MAXIMUM RATINGS

Any exceeding absolute maximum rating application causes permanent damage to device. Because long-time absolute operation state affects device reliability. Absolute ratings just conclude from a series of extreme tests. It doesn't represent chip can operate normally in these extreme conditions.

Parameter	Symbol	Ratings	Unit
Power Supply	VDD-VSS	7.0	V
Current on Input Pin		±2.0	mA
Analog Input	VIN+, VIN-	VSS-1.0 ~ VDD+1.0	V
Other Input and Output		VSS-0.3 ~ VDD+0.3	V
Differential Input Voltage		VDD-VSS	V
Current on Output and Power Supply Pins		±30	mA
Storage Temperature	T _{stg}	-60 ~ +150	°C
Operating Temperature Range	T _{opr}	-40 ~ +120	°C
ESD	HBM	>3k	V

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Range			Unit
		Min	Typ	Max	
Power Supply	VDD	1.8	5	5.5	V

ELECTRICAL CHARACTERISTICS

$V_{DD}=1.8V$ to $5.5V$, $V_{SS}=GND$, $V_{CM}=V_{DD}/2$, $V_{OUT}=V_{DD}/2$, $V_L=V_{DD}/2$, $R_L=1M\Omega$ to V_L .

Unless otherwise noted, the temperature $T_A=25^{\circ}C\pm 2^{\circ}C$.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Input Characteristics						
Input Offset Voltage	V _{OS}	V _{DD} =3V, V _{CM} =1.5V	-0.5		+0.5	mV
		V _{DD} =1.8V ~ 5.5V, V _{CM} =V _{DD} /2	-0.75		+0.75	
Input Bias Current	I _B	V _{DD} =5V		0.74		pA
		V _{DD} =1.8V		0.36		
Input Offset Current	I _{OS}	V _{DD} =5V		0.15		pA
		V _{DD} =1.8V		0.18		
Common-mode Rejection Ratio	CMRR	-0.3V< V _{CM} <2.1V, V _{DD} =1.8V	67	80		dB
		-0.3V< V _{CM} <5.8V, V _{DD} =5.5V	80	90		
		2.75V< V _{CM} <5.8V, V _{DD} =5.5V	70	89		
		-0.3V< V _{CM} <2.75V, V _{DD} =5.5V	72	93		
Common-mode Input Voltage Range	V _{CMR}		-0.3		5.8	V
Large Signal Gain	A _{OL}	R _L = 50kΩ to V _L , 0.2V< V _{OUT} <(V _{DD} -0.2V)	95			dB
Input Offset Voltage Drift	ΔV _{OS} /ΔT	-40℃ to 120℃		±3.0		μV/℃
Input Impedance	Z _{DIFF}			1013 6		Ω pF
	Z _{CM}			1013 6		Ω pF
Output Characteristics						
Output High-level Voltage	V _{OH}	R _L = 50kΩ to V _L		V _{DD} -10		mV
Output Low-level Voltage	V _{OL}	R _L = 50kΩ to V _L		V _{SS} +10		mV
Output Short-circuit Current	I _{SC}	V _{DD} =1.8V, V _{IN+} =1V, V _{IN-} =1.8V		±6		mA
		V _{DD} =1.8V, V _{IN+} =1.8V, V _{IN-} =1V		±8		
		V _{DD} =5.5V, V _{IN+} =2V, V _{IN-} =1V		±25		
		V _{DD} =5.5V, V _{IN+} =1V, V _{IN-} =2V		±52		
Power Supply						
Power Supply	V _{DD}		1.8		5.5	V
Power Supply Rejection Ratio	PSRR	V _{CM} = V _{SS}	70	92		dB
Quiescent Current/Amplifier	I _{SY}	I _O =0, V _{CM} = V _{DD} , V _{DD} =5.5V		1	1.4	μA

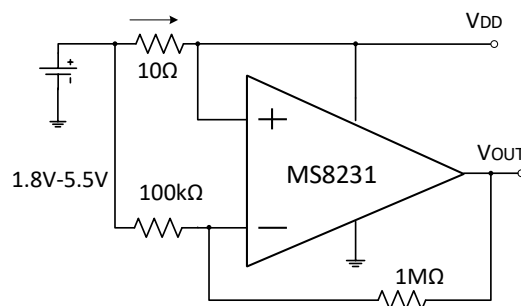
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Dynamic Characteristics						
Gain Bandwidth	GBW	VDD=5V, AV=1, VPP=2V, -3dB		13		kHz
Slew Rate	SR	RL= 1MΩ, CL=65pF, Rising Edge		3		V/ms
	SR	RL= 1MΩ, CL=65pF, Falling Edge		5		V/ms
Phase Margin	Φ _O			65		Deg
Noise Characteristics						
Input Voltage Noise	en p-p	f=0.1Hz to 10Hz		5		μVp-p
Voltage Noise Density	en	f = 1kHz		165		nV/√Hz
Current Noise Density	in	f = 1kHz		0.6		fA/√Hz

TYPICAL APPLICATION

Battery Current Detection

This kind of amplifier has wide common-mode input voltage, which is suitable for being used in high-side and low-side battery current detector. Its ultra-low quiescent current can prolong battery life. And its rail-to-rail output can be used to detect low current.

The battery current detection circuit is shown in Figure 1. 10Ω resistance minimizes power dissipation. Battery current, I_{DD} passes through 10Ω resistor and causes voltage drop. The common-mode input voltage of operational amplifier is kept below V_{DD} within the allowable range. Within the maximum output voltage range, the output is also below V_{DD} .



$$I_{DD} = \frac{V_{DD} - V_{OUT}}{(10V/V) \times (10\Omega)}$$

Figure 1. Battery Current Detection Circuit

High-Precision Comparator

In front end of comparator, operational amplifier with high gain can be used to improve the input offset performance and precision. The circuit diagram is shown in Figure 2, the gain is 11V/V.

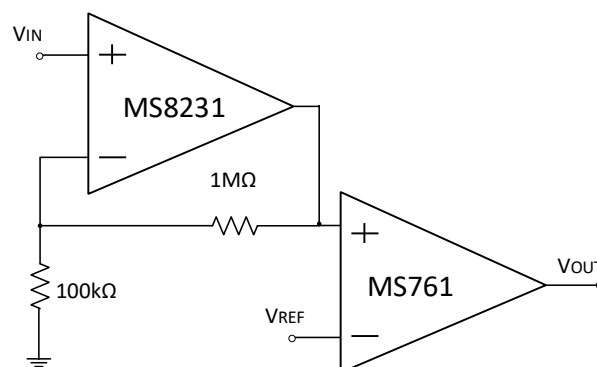
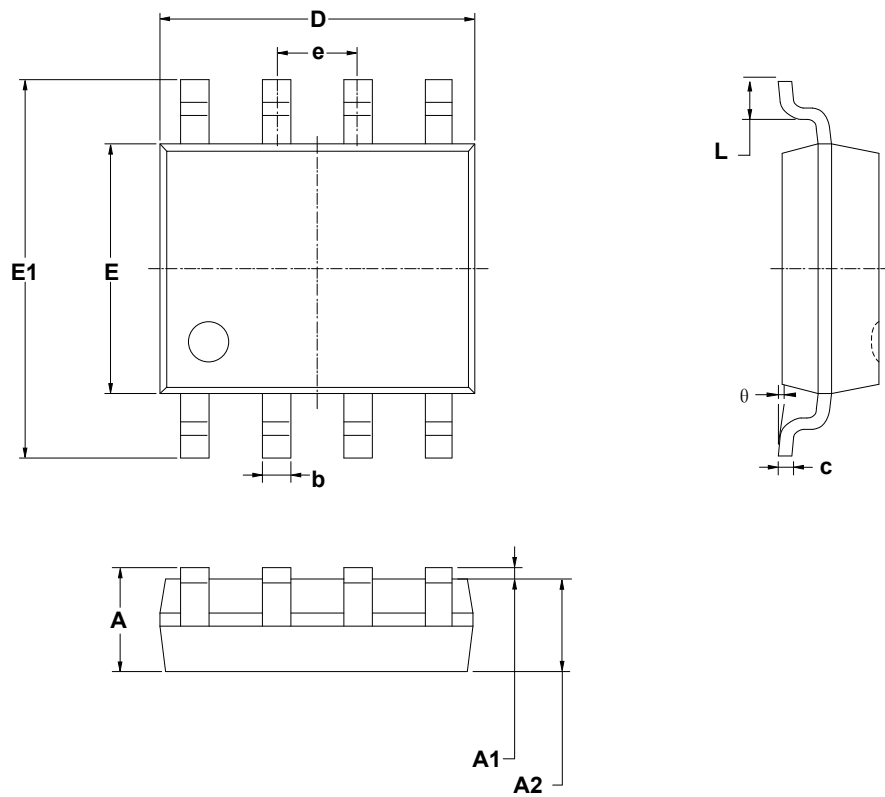


Figure 2. High-precision Comparator

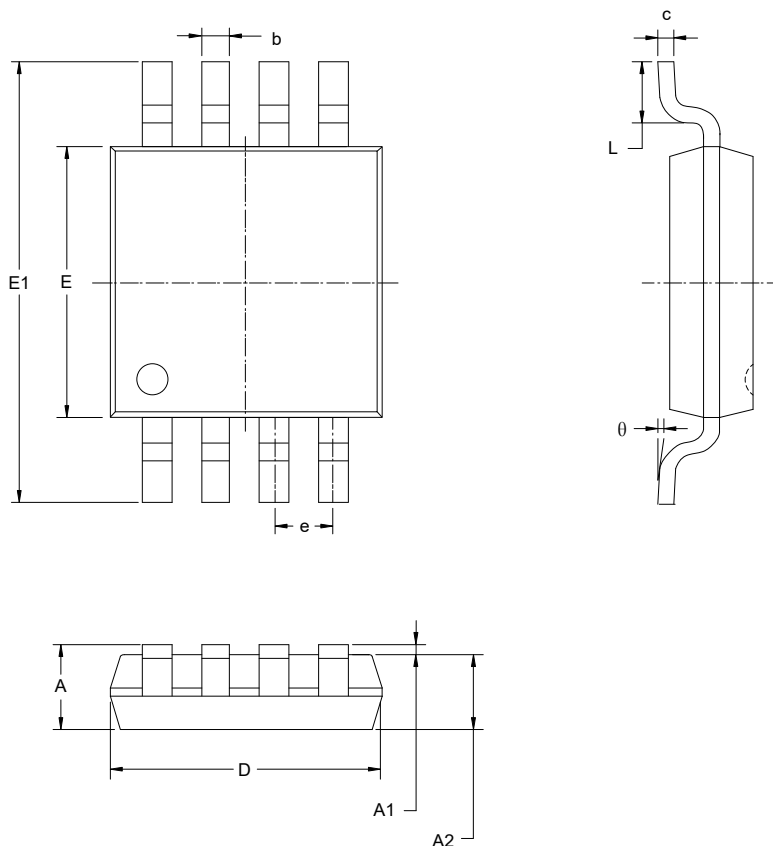
PACKAGE OUTLINE DIMENSIONS

SOP8



Symbol	Dimensions in Millimeters		
	Min	Typ	Max
A	-	-	1.75
A1	0.10	-	0.225
A2	1.30	1.40	1.50
b	0.39	-	0.47
c	0.20	-	0.24
D	4.80	4.90	5.00
E	3.80	3.90	4.00
E1	5.80	6.00	6.20
e	1.27BSC		
L	0.50	-	0.80
θ	0°	-	8°

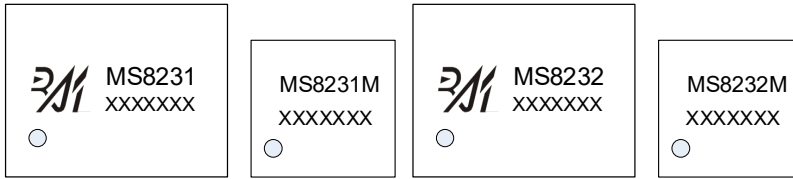
MSOP8



Symbol	Dimensions in Millimeters		
	Min	Typ	Max
A	-	-	1.10
A1	0.05	-	0.15
A2	0.75	0.85	0.95
b	0.28	-	0.36
c	0.15	-	0.19
D	2.90	3.00	3.10
E	2.90	3.00	3.10
E1	4.70	4.90	5.10
e	0.65BSC		
L	0.40	-	0.70
θ	0°	-	8°

MARKING and PACKAGING SPECIFICATION

1. Marking Drawing Description



Product Name: MS8231, MS8231M, MS8232, MS8232M

Product Code: XXXXXX

2. Marking Drawing Demand

Laser printing, contents in the middle, font type Arial.

3. Packaging Specification

Device	Package	Piece/Reel	Reel/Box	Piece/Box	Box/Carton	Piece/Carton
MS8231	SOP8	2500	1	2500	8	20000
MS8231M	MSOP8	3000	1	3000	8	24000
MS8232	SOP8	2500	1	2500	8	20000
MS8232M	MSOP8	3000	1	3000	8	24000

STATEMENT

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- When using Ruimeng products to design and produce, purchaser has the responsibility to observe safety standard and adopt corresponding precautions, in order to avoid personal injury and property loss caused by potential failure risk.
- The process of improving product is endless. And our company would sincerely provide more excellent product for customer.

**MOS CIRCUIT OPERATION PRECAUTIONS**

Static electricity can be generated in many places. The following precautions can be taken to effectively prevent the damage of MOS circuit caused by electrostatic discharge:

1. The operator shall ground through the anti-static wristband.
2. The equipment shell must be grounded.
3. The tools used in the assembly process must be grounded.
4. Must use conductor packaging or anti-static materials packaging or transportation.



+86-571-89966911



Rm701, No.9 Building, No. 1 WeiYe Road, Puyan Street, Binjiang District, Hangzhou, Zhejiang



[http:// www.relmon.com](http://www.relmon.com)